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# FDN336P

# Single P-Channel 2.5V Specified PowerTrench® MOSFET

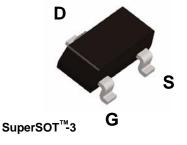
## **General Description**

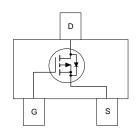
This P-Channel 2.5V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

These devices are well suited for portable electronics applications: load switching and power management, battery charging circuits and DC/DC conversion.

## **Features**

- -1.3 A, -20 V.  $R_{DS(ON)}$  = 0.20 Ω @  $V_{GS}$  = -4.5 V  $R_{DS(ON)}$  = 0.27 Ω @  $V_{GS}$  = -2.5 V
- Low gate charge (3.6 nC typical)
- High performance trench technology for extremely low R<sub>DS(ON)</sub>
- SuperSOT<sup>TM</sup> -3 provides low R<sub>DS(ON)</sub> and 30% higher power handling capability than SOT23 in the same footprint





Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		-20	V
V <sub>GSS</sub>	Gate-Source Voltage		±8	V
I <sub>D</sub>	Drain Current - Continuous	(Note 1a)	-1.3	А
	- Pulsed		-10	
P <sub>D</sub>	Maximum Power Dissipation	(Note 1a)	0.5	W
		(Note 1b)	0.46	
$T_J, T_{STG}$	Operating and Storage Junction Tem	perature Range	-55 to +150	°C

# **Thermal Characteristics**

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	250	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	75	°C/W

**Package Marking and Ordering Information** 

Device Marking	Device	Reel Size	Tape width	Quantity	
336	FDN336P	7"	8mm	3000 units	

Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAR	ACTERISTICS						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$		-20			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_D = -250 \mu\text{A}$ , Referenced to	o 25 ℃		-16		mV /°C
DSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -16 V, V <sub>GS</sub> = 0 V				-1	μA
			T <sub>J</sub> = 55°C			-10	μΑ
GSSF	Gate - Body Leakage, Forward	$V_{GS} = 8 \text{ V}, V_{DS} = 0 \text{ V}$	•			100	nA
GSSR	Gate - Body Leakage, Reverse	$V_{GS} = -8 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
ON CHARA	CTERISTICS (Note 2)						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$		-0.4	-0.9	-1.5	V
$\Delta V_{GS(th)}/\Delta T_{J}$	Gate Threshold Voltage Temp. Coefficient	$I_D = -250 \mu\text{A}$ , Referenced to	o 25 °C		3		mV /°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	tance $V_{GS} = -4.5 \text{ V}, I_{D} = -1.3 \text{ A}$			0.122	0.2	Ω
()			T <sub>J</sub> =125°C		0.18	0.32	
		$V_{GS} = -2.5 \text{ V}, I_D = -1.1 \text{ A}$	•		0.19	0.27	
D(ON)	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, \ V_{DS} = -5 \text{ V}$		-5			Α
) <sub>FS</sub>	Forward Transconductance	$V_{DS} = -4.5 \text{ V}, I_{D} = -2 \text{ A}$			4		S
OYNAMIC C	HARACTERISTICS						
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1.0 \text{ MHz}$			330		pF
Coss	Output Capacitance				80		pF
C <sub>rss</sub>	Reverse Transfer Capacitance				35		pF
SWITCHING	CHARACTERISTICS (Note 2)						
D(on)	Turn - On Delay Time	$V_{DD} = -5 \text{ V}, I_{D} = -0.5 \text{ A},$			7	15	ns
r	Turn - On Rise Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$			12	22	ns
D(off)	Turn - Off Delay Time				16	26	ns
f	Turn - Off Fall Time				5	12	ns
$Q_g$	Total Gate Charge	$V_{DS} = -10 \text{ V}, I_D = -2 \text{ A}, V_{GS} = -4.5 \text{ V}$			3.6	5	nC
$Q_{gs}$	Gate-Source Charge				8.0		nC
$Q_{gd}$	Gate-Drain Charge				0.7		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS AND MAX	KIMUM RATINGS			1		1
S	Maximum Continuous Drain-Source Diode Fo	rward Current				-0.42	Α
$V_{SD}$	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, \ I_S = -0.42 \text{ A} \ \ \text{(Note)}$			-0.7	-1.2	V

<sup>1.</sup> R<sub>a.u.</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>a.c.</sub> is guaranteed by design while  $\boldsymbol{R}_{\scriptscriptstyle{\theta CA}}$  is determined by the user's board design.



a. 250°C/W when mounted on a 0.02 in² pad of 2oz Cu.



b. 270°C/W when mounted on a 0.001 in² pad of 2oz Cu.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2.0%.

# **Typical Electrical Characteristics**

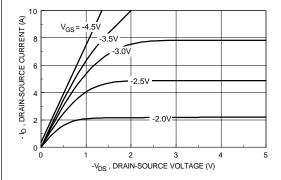


Figure 1. On-Region Characteristics.

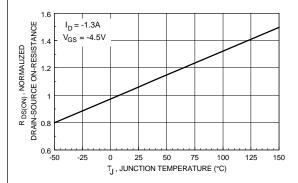


Figure 3. On-Resistance Variation with Temperature.

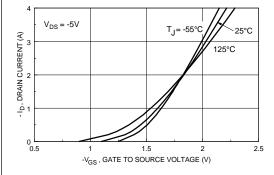


Figure 5. Transfer Characteristics.

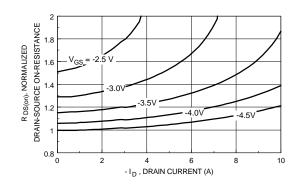


Figure 2. On-Resistance Variation with Drain Current and Gate

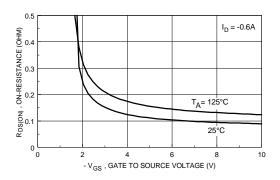


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

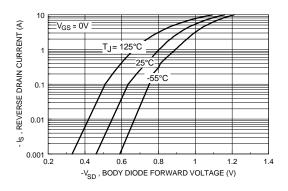


Figure 6. Body Diode Forward Voltage

Variation with Source

Current

and Temperature.

# **Typical Electrical Characteristics** (continued)

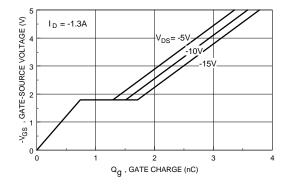


Figure 7. Gate Charge Characteristics.

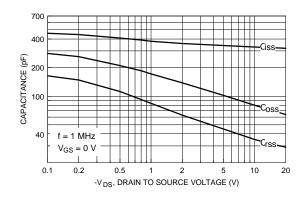


Figure 8. Capacitance Characteristics.

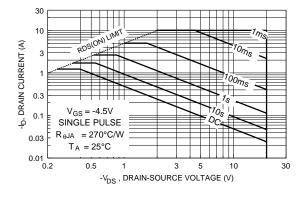


Figure 9. Maximum Safe Operating Area.

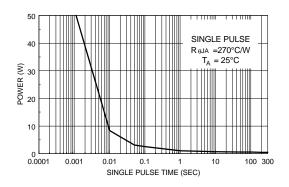


Figure 10. Single Pulse Maximum Power Dissipation.

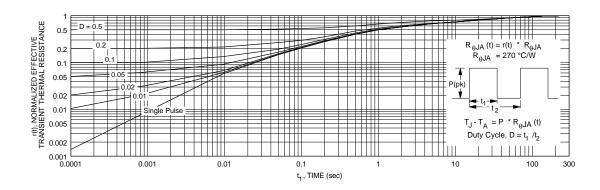


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.

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